

# QM50TB-24B

MEDIUM POWER SWITCHING USE  
INSULATED TYPE

## QM50TB-24B



- **IC** Collector current ..... **50A**
- **V<sub>CEX</sub>** Collector-emitter voltage ..... **1200V**
- **h<sub>FE</sub>** DC current gain ..... **750**
- **Insulated Type**
- **UL Recognized**

Yellow Card No. E80276 (N)

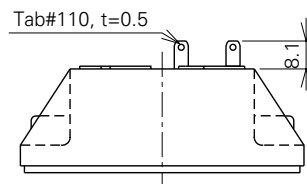
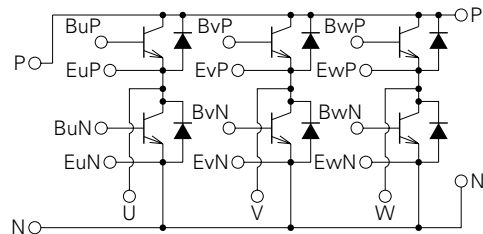
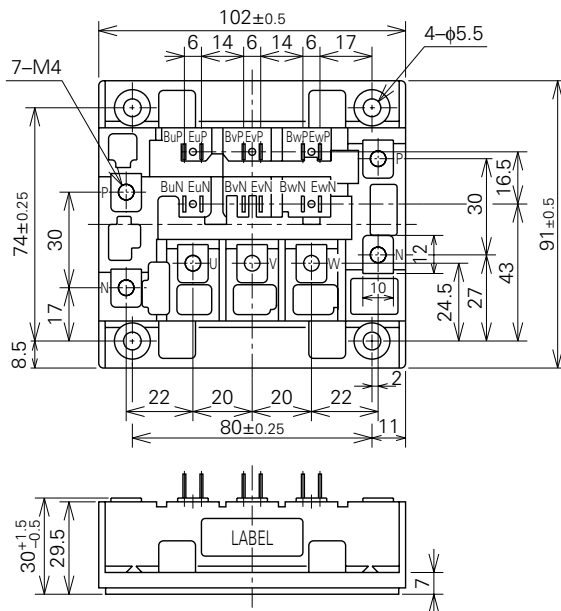
File No. E80271

## APPLICATION

Inverters, Servo drives, DC motor controllers, NC equipment, Welders

## OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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## ABSOLUTE MAXIMUM RATINGS (Tj=25°C, unless otherwise noted)

| Symbol     | Parameter                                               | Conditions                                  | Ratings   | Unit  |
|------------|---------------------------------------------------------|---------------------------------------------|-----------|-------|
| VCEX (SUS) | Collector-emitter voltage                               | IC=1A, VEB=2V                               | 1200      | V     |
| VCEX       | Collector-emitter voltage                               | VEB=2V                                      | 1200      | V     |
| VCBO       | Collector-base voltage                                  | Emitter open                                | 1200      | V     |
| VEBO       | Emitter-base voltage                                    | Collector open                              | 7         | V     |
| IC         | Collector current                                       | DC                                          | 50        | A     |
| -IC        | Collector reverse current                               | DC (forward diode current)                  | 50        | A     |
| PC         | Collector dissipation                                   | Tc=25°C                                     | 400       | W     |
| IB         | Base current                                            | DC                                          | 3         | A     |
| -ICSM      | Surge collector reverse current (forward diode current) | Peak value of one cycle of 60Hz (half wave) | 500       | A     |
| Tj         | Junction temperature                                    |                                             | -40~+150  | °C    |
| Tstg       | Storage temperature                                     |                                             | -40~+125  | °C    |
| Viso       | Isolation voltage                                       | Charged part to case, AC for 1 minute       | 2500      | V     |
| —          | Mounting torque                                         | Main terminal screw M4                      | 0.98~1.47 | N·m   |
|            |                                                         |                                             | 10~15     | kg·cm |
|            |                                                         | Mounting screw M5                           | 1.47~1.96 | N·m   |
|            |                                                         |                                             | 15~20     | kg·cm |
| —          | Weight                                                  | Typical value                               | 660       | g     |

## ELECTRICAL CHARACTERISTICS (Tj=25°C, unless otherwise noted)

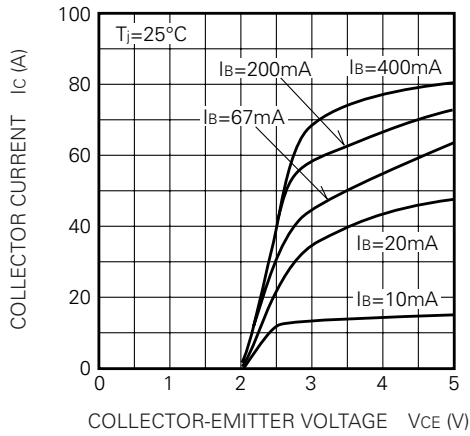
| Symbol      | Parameter                                | Test conditions                            | Limits |      |      | Unit |
|-------------|------------------------------------------|--------------------------------------------|--------|------|------|------|
|             |                                          |                                            | Min.   | Typ. | Max. |      |
| ICEX        | Collector cutoff current                 | VCE=1200V, VEB=2V                          | —      | —    | 2.0  | mA   |
| ICBO        | Collector cutoff current                 | VCB=1200V, Emitter open                    | —      | —    | 2.0  | mA   |
| IEBO        | Emitter cutoff current                   | VEB=7V                                     | —      | —    | 50   | mA   |
| VCE (sat)   | Collector-emitter saturation voltage     | IC=50A, IB=67mA                            | —      | —    | 4.0  | V    |
| VBE (sat)   | Base-emitter saturation voltage          |                                            | —      | —    | 4.0  | V    |
| -VCEO       | Collector-emitter reverse voltage        | -IC=50A (diode forward voltage)            | —      | —    | 1.8  | V    |
| hFE         | DC current gain                          | IC=50A, VCE=4.0V                           | 750    | —    | —    | —    |
| ton         | Switching time                           | VCC=600V, IC=50A, IB1=0.1mA, -IB2=1.0A     | —      | —    | 2.5  | μs   |
| ts          |                                          |                                            | —      | —    | 15   | μs   |
| tr          |                                          |                                            | —      | —    | 3.0  | μs   |
| Rth (j-c) Q | Thermal resistance (junction to case)    | Transistor part (per 1/6 module)           | —      | —    | 0.31 | °C/W |
| Rth (j-c) R |                                          | Diode part (per 1/6 module)                | —      | —    | 1.2  | °C/W |
| Rth (c-f)   | Contact thermal resistance (case to fin) | Conductive grease applied (per 1/6 module) | —      | —    | 0.2  | °C/W |

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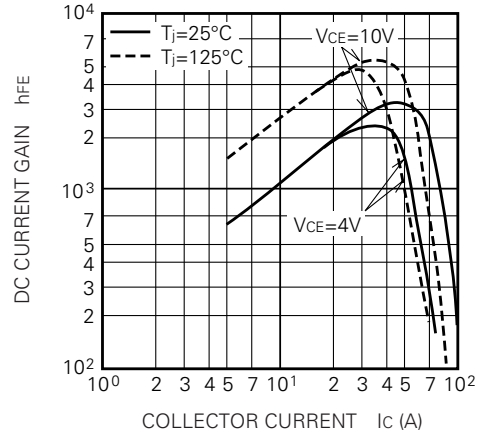
MEDIUM POWER SWITCHING USE  
INSULATED TYPE

## PERFORMANCE CURVES

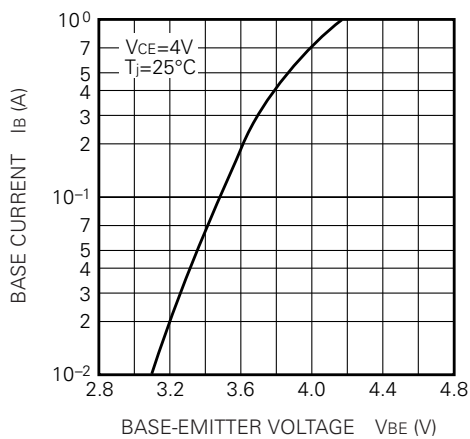
COMMON EMITTER OUTPUT  
CHARACTERISTICS (TYPICAL)



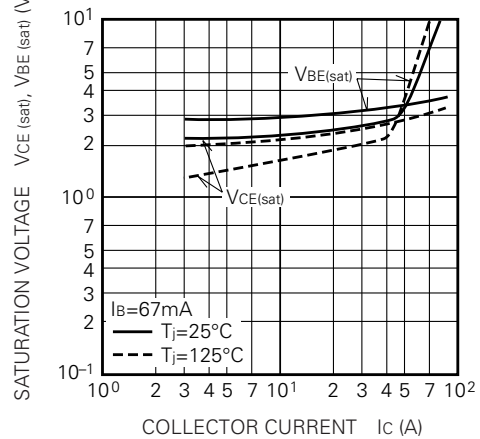
DC CURRENT GAIN VS.  
COLLECTOR CURRENT (TYPICAL)



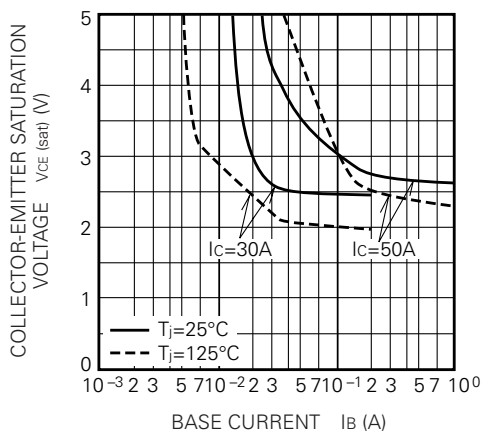
COMMON EMITTER INPUT  
CHARACTERISTIC (TYPICAL)



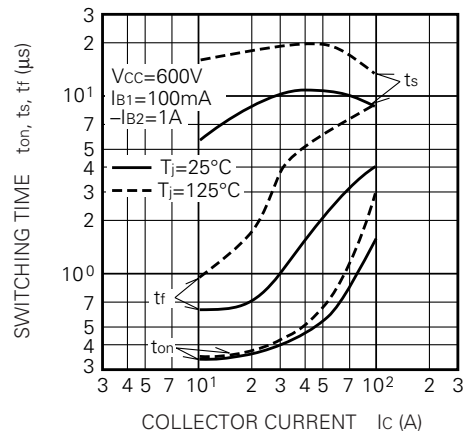
SATURATION VOLTAGE  
CHARACTERISTICS (TYPICAL)



COLLECTOR-EMITTER SATURATION  
VOLTAGE (TYPICAL)



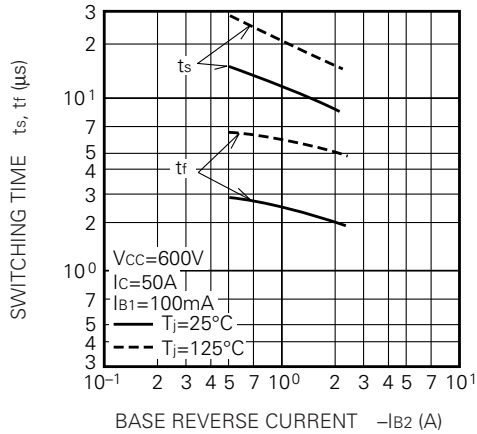
SWITCHING TIME VS. COLLECTOR  
CURRENT (TYPICAL)



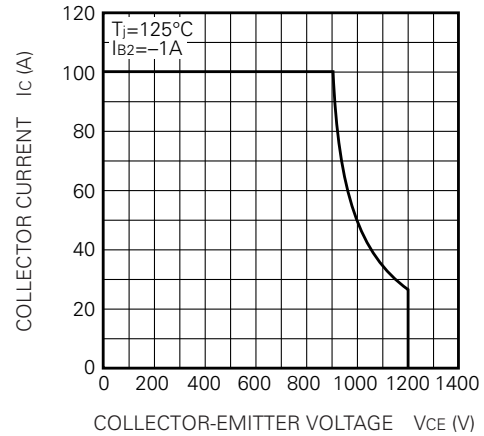
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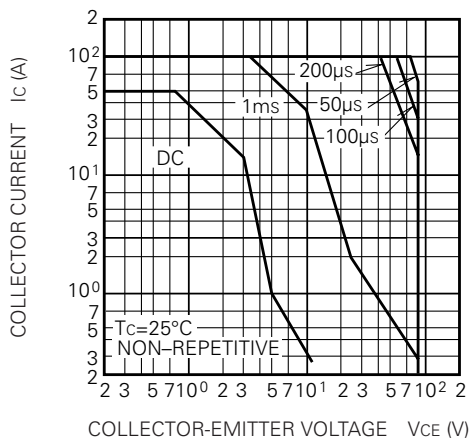
SWITCHING TIME VS. BASE CURRENT (TYPICAL)



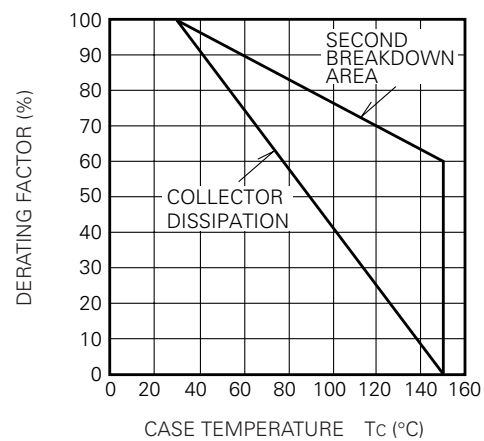
REVERSE BIAS SAFE OPERATING AREA



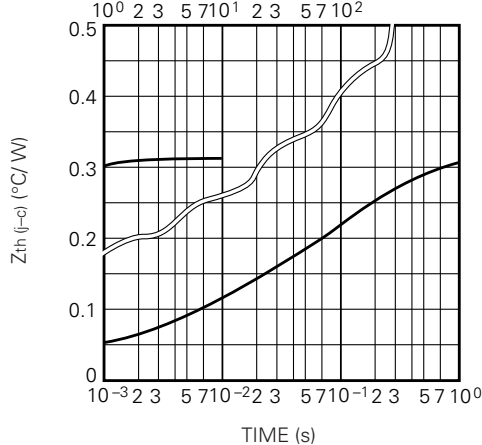
FORWARD BIAS SAFE OPERATING AREA



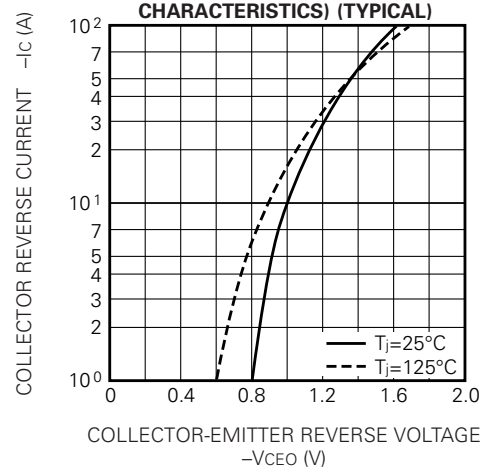
DERATING FACTOR OF F. B. S. O. A.



TRANSIENT THERMAL IMPEDANCE CHARACTERISTIC (TRANSISTOR)



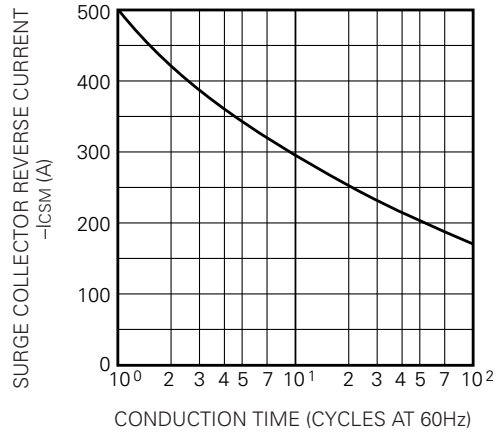
REVERSE COLLECTOR CURRENT VS. COLLECTOR-EMITTER REVERSE VOLTAGE (DIODE FORWARD CHARACTERISTICS) (TYPICAL)



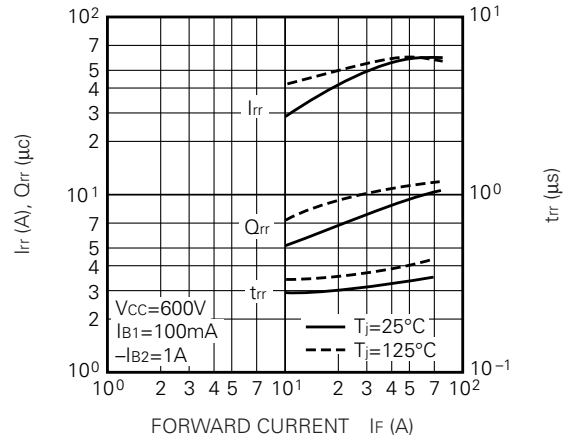
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**RATED SURGE COLLECTOR REVERSE CURRENT  
(DIODE FORWARD SURGE CURRENT)**



**REVERSE RECOVERY CHARACTERISTICS  
OF FREE-WHEEL DIODE (TYPICAL)**



**TRANSIENT THERMAL IMPEDANCE  
CHARACTERISTICS (DIODE)**

